Sheet to

Write down expression for the B- and H- plane patterns for a uniformly aminated rectangular aperture.

b- For a uniformly illuminated 53.32 rectangular aperture with y- polarized electrical

11-Find and sketch the field pattern in both E and H planes. 11-Estimate the 3-dB beam width and the gain.

2-For a uniformly illuminated circular aperture (a=3λ) with y- polarized electric field:

7-Find and sketch the field pattern in both E and H planes. ii-Estimate the 3-dB beam width and the gain.

Phase shift $e^{j\pi \sqrt{2}}$ and a square blockage $(2\lambda*2\lambda)$ in the center and the aperture electric field is polarized in y-direction. Derive expressions for the far field patterns in the x-z and y-z planes indicating the E and H planes.

for a uniform illumination rectangular aperture, if the E field is y polarized, the 30 beam width in the H plane is assumed to be 10.2° and directivity is 22.753dB. Find the aperture dimensions and sketch the E and H plane patterns.

5-Drive expressions for the E and H plane patterns of a rectangular aperture if:

 $\underline{\underline{E}}(x',y') = E_{ari} \frac{y'}{b/2} \hat{x}$ electric Colo

brive expressions for the E and H plane patterns of the uniformly illuminated circular aperture with a center blockage as shown in figure.